TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SGU04AFS

Inverter (Un-Buffer)

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

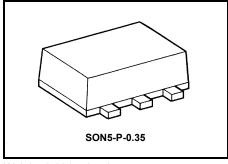
at V_{CC} = 3 V

• High-speed operation: t_{pd} = 1.9 ns (typ.)

at V_{CC} = 3.3 V,15pF

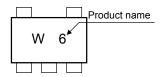
• Operating voltage range: V_{CC} = 0.9~3.6 V

• 3.6-V tolerant inputs

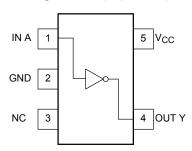


Weight: 0.001 g (typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage	V _{IN}	-0.5~4.6	V	
DC output voltage	V _{OUT}	-0.5~ V _{CC} + 0.5	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	lok	±20 (Note 1)	mA	
DC output current	I _{OUT}	±25	mA	
DC V _{CC} /ground current	Icc	±50	mA	
Power dissipation	PD	50	mW	
Storage temperature	T _{stg}	-65~150	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

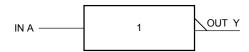
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{OUT} < GND, V_{OUT} > V_{CC}

Truth Table

A Y L H H L

IEC Logic Symbol



Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~3.6	٧	
Output voltage	V _{OUT}	0~V _{CC}	٧	
Output Current		±8.0 (Note 2)		
		±4.0 (Note 3)		
	1//	±3.0 (Note 4)	mA	
	I _{OH} /I _{OL}	±1.7 (Note 5)	IIIA	
		±0.3 (Note 6)		
		±0.02 (Note 7)		
Operating temperature	T _{opr}	-40~85	°C	

Note 2: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 3: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 4: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 5: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 6: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 7: $V_{CC} = 0.9 \text{ V}$



DC Electrical Characteristics

Characteristics Symbol Test Condi		Condition	ondition		Ta = 25°0	2	Ta = -40~85°C		Unit	
		1030	V _C		Min	Тур.	Max	Min	Max	Offic
High-level VIH input voltage		_		0.9	Vcc		_	Vcc	_	
				1.1~1.3	V _{CC} × 0.8	_	_	V _{CC} × 0.8		
				1.4~1.6	V _{CC} × 0.8	_	_	V _{CC} × 0.8	_	
	V _{IH}			1.65~ 1.95	V _{CC} × 0.8	_	_	V _{CC} × 0.8	_	V
				2.3~2.7	V _{CC} × 0.8	_	_	V _{CC} × 0.8	_	
				V _{CC} × 0.8	_	_	V _{CC} × 0.8	_		
				0.9	_	_	GND	_	GND	
Low-level				_	_	V _{CC} × 0.2	_	V _{CC} × 0.2		
				_	_	V _{CC} × 0.2	_	V _{CC} × 0.2		
input voltage	V _{IL}		_	1.65~ 1.95	_	_	V _{CC} × 0.2	_	V _{CC} × 0.2	V
				_		V _{CC} × 0.2	_	V _{CC} × 0.2		
				3.0~3.6	_	_	V _{CC} × 0.2	_	V _{CC} × 0.2	
		$V_{IN} = V_{IL} \\$	I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	_	
High-level V _C output voltage	V _{OH}	V _{IN} =GND	$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	V
			$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75		_	V _{CC} × 0.75		
			$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45		
			$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0		_	2.0	_	
			$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48			2.48	_	
Low-level output voltage		$V_{IN} = V_{IH} \\$	$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	2.5 2.5 V
			$I_{OL} = 0.3 \text{ mA}$	1.1~1.3	_	_	V _{CC} × 0.25	_	V _{CC} × 0.25	
	V _{OL}		I _{OL} = 1.7 mA	1.4~1.6	_	_	V _{CC} × 0.25	_	V _{CC} × 0.25	
		V _{IN} = V _{CC}	I _{OL} = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45	
			$I_{OL} = 4.0 \text{ mA}$	2.3~2.7	_	_	0.4	_	0.4	
			I _{OL} = 8.0 mA	3.0~3.6		_	0.4	_	0.4	
Input leakage current	I _{IN}	V _{IN} = 0~3.6V		0~3.6	_	_	±0.1	_	±1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$	or GND	3.6	_	_	1.0	_	10.0	μА

AC Electrical Characteristics (input $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
			V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
		C_L = 10 pF, R_L = 1 M Ω	0.9	_	15.0	_	_	_	
			1.1~1.3	_	6.0	18.4	1.0	34.2	
			1.4~1.6	_	3.2	8.5	1.0	10.0	
			1.65~ 1.95	_	2.6	6.2	1.0	6.7	
			2.3~2.7	_	2.0	3.9	1.0	4.4	
			3.0~3.6	_	1.7	3.1	1.0	3.7	
		C_L = 15 pF, R_L = 1 M Ω	0.9	_	18.8	_	_	_	
			1.1~1.3	_	7.0	21.5	1.0	37.2	ns
Propagation delay time	tpLH tpHL		1.4~1.6		3.5	9.3	1.0	11.2	
			1.65~ 1.95		3.0	6.9	1.0	7.1	
			2.3~2.7	_	2.3	4.4	1.0	5.0	
			3.0~3.6	_	1.9	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	33.0	_	_	_	
			1.1~1.3		12.0	29.6	1.0	56.0	
			1.4~1.6		6.0	13.1	1.0	15.9	
			1.65~ 1.95		4.5	9.2	1.0	9.6	
			2.3~2.7	_	3.2	5.7	1.0	6.1	
			3.0~3.6	_	2.5	4.4	1.0	4.8	
Input capacitance	C _{IN}	_	3.6	_	3	_	_	_	pF
Power dissipation capacitance	C _{PD}	(Note8)	0.9~3.6		8	_	_	_	pF

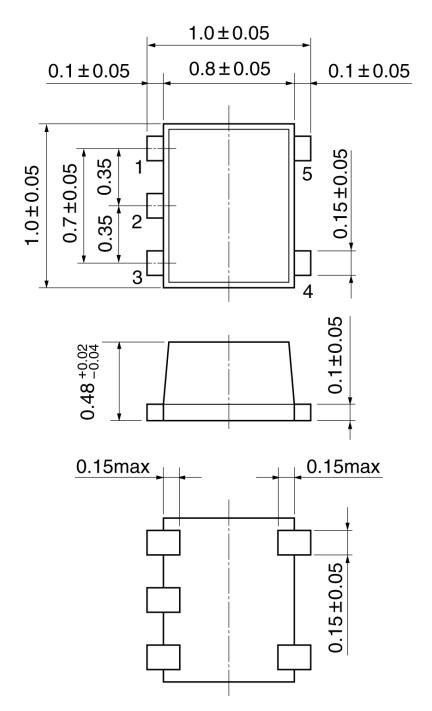
Note 8: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

SON5-P-0.35 Unit:mm



Weight: 0.001 g (typ.)

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20070701-EN GENERAL

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